



Enhancing the Electronic-Coupling and Band Gap Tunability of Ferrocenyl Molecular Ultra-Thin Film with Pd and Cu Doping

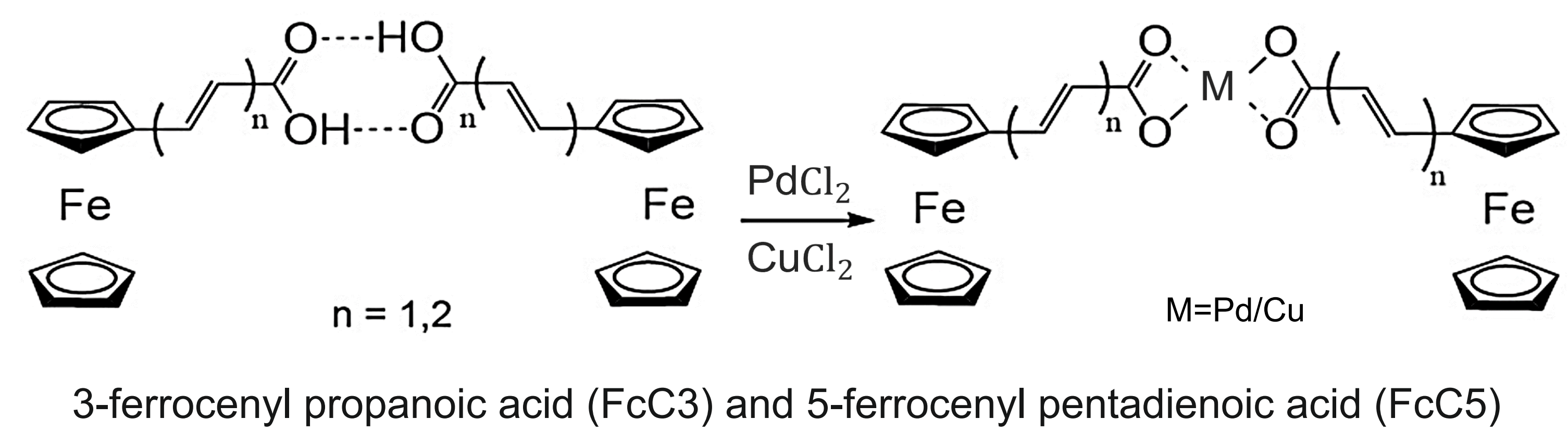
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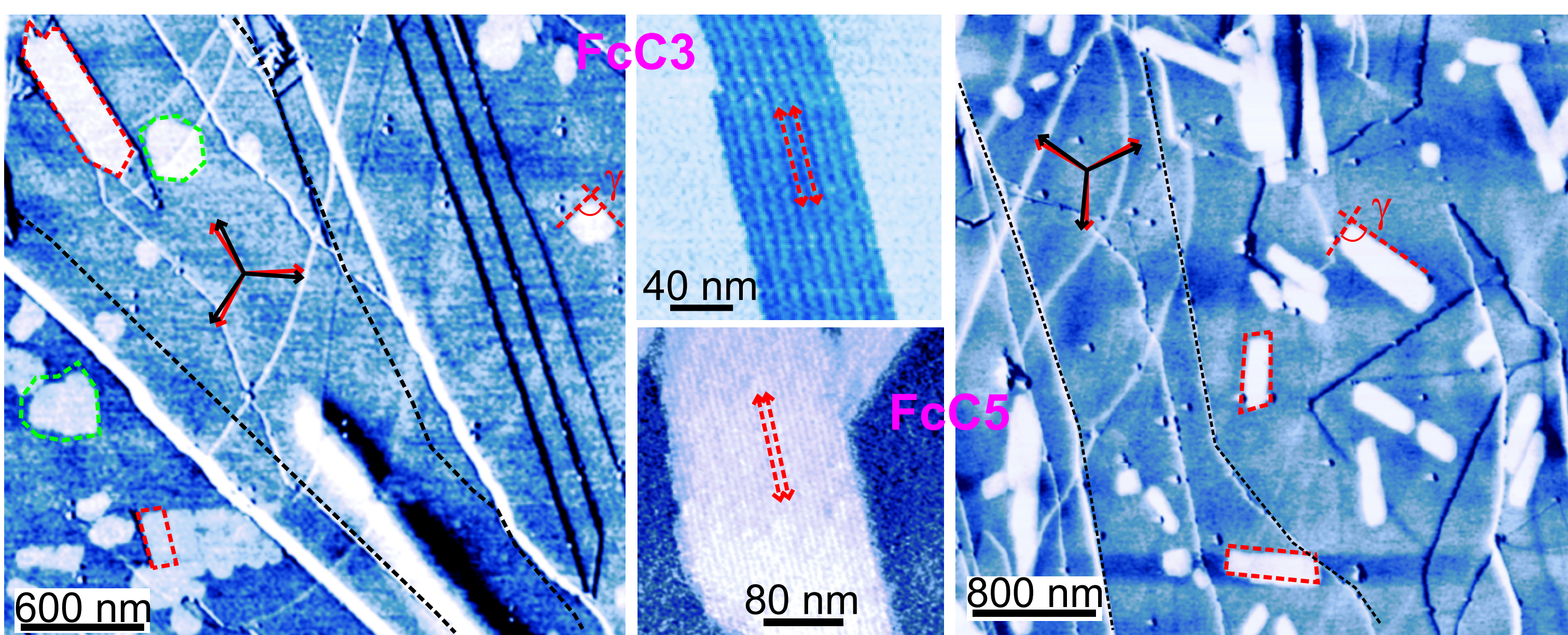
Introduction

- To improve charge transport in molecular film, metal dopants are introduced at specific ligand sites. This enhances the electronic coupling between the molecules, leading to better charge transport.
- Carboxyl functional group ($-\text{COOH}$) is suitable for metal doping, as it offers a four-fold coordination site. It has been effectively used in the formation of Surface confined Metal-Organic Network (SMON) on surfaces.
- Two ferrocenyl molecules, 3-ferrocenyl propanoic acid (FcC3) and 5-ferrocenyl pentadienoic acid (FcC5) are used for creating Pd and Cu SMON.

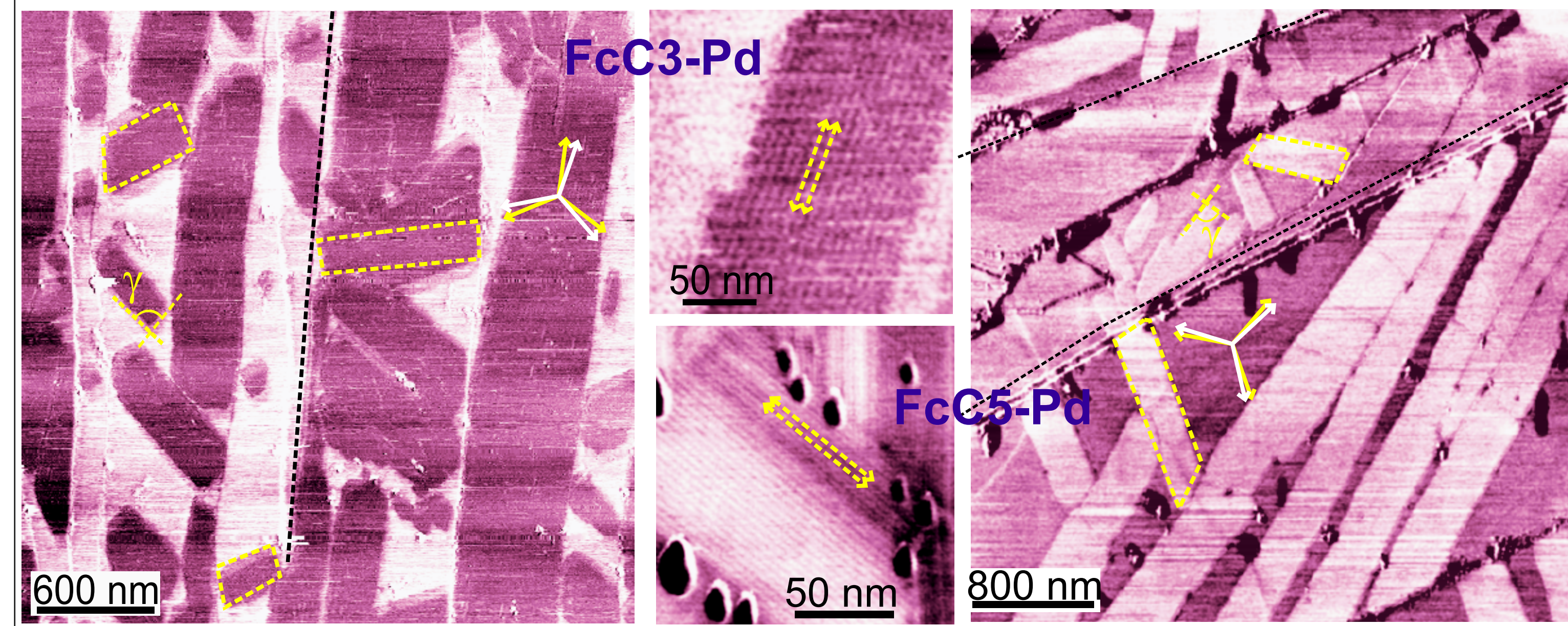
Scheme of preparation



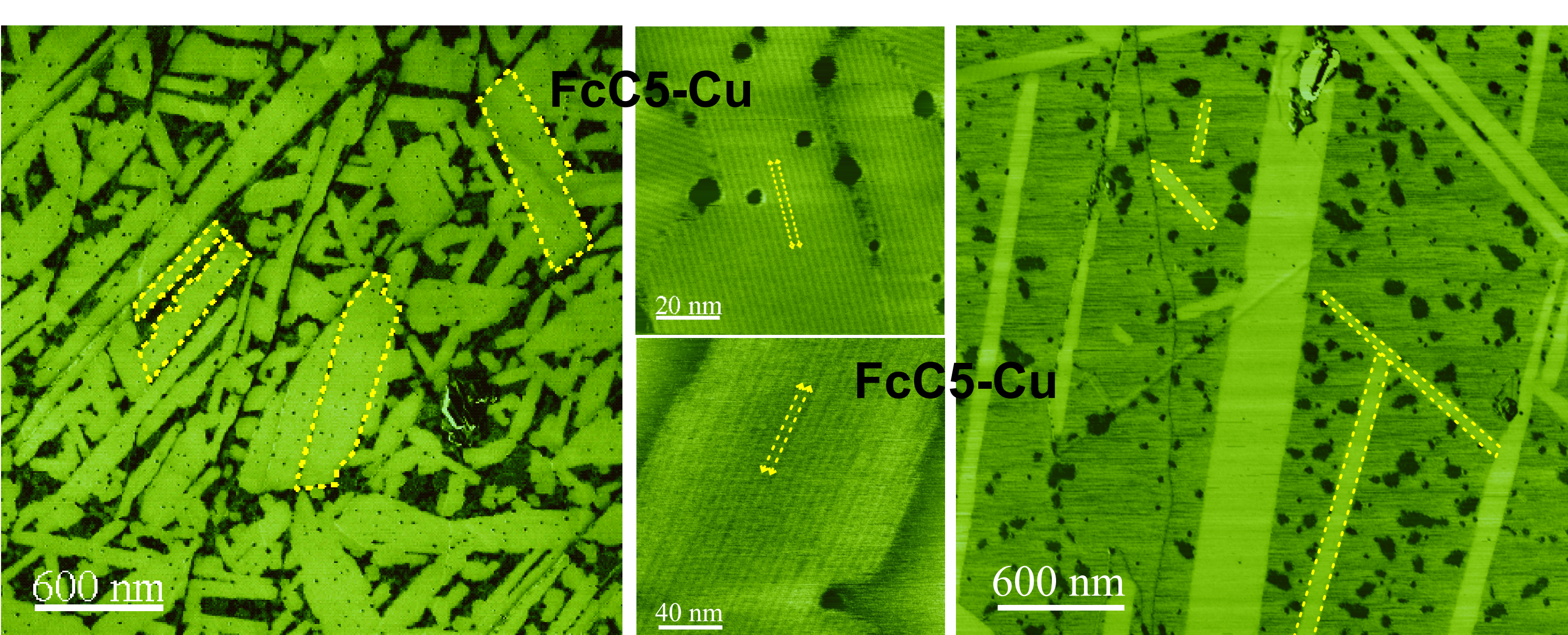
AFM phase images of adlayer of FcC3 and FcC5



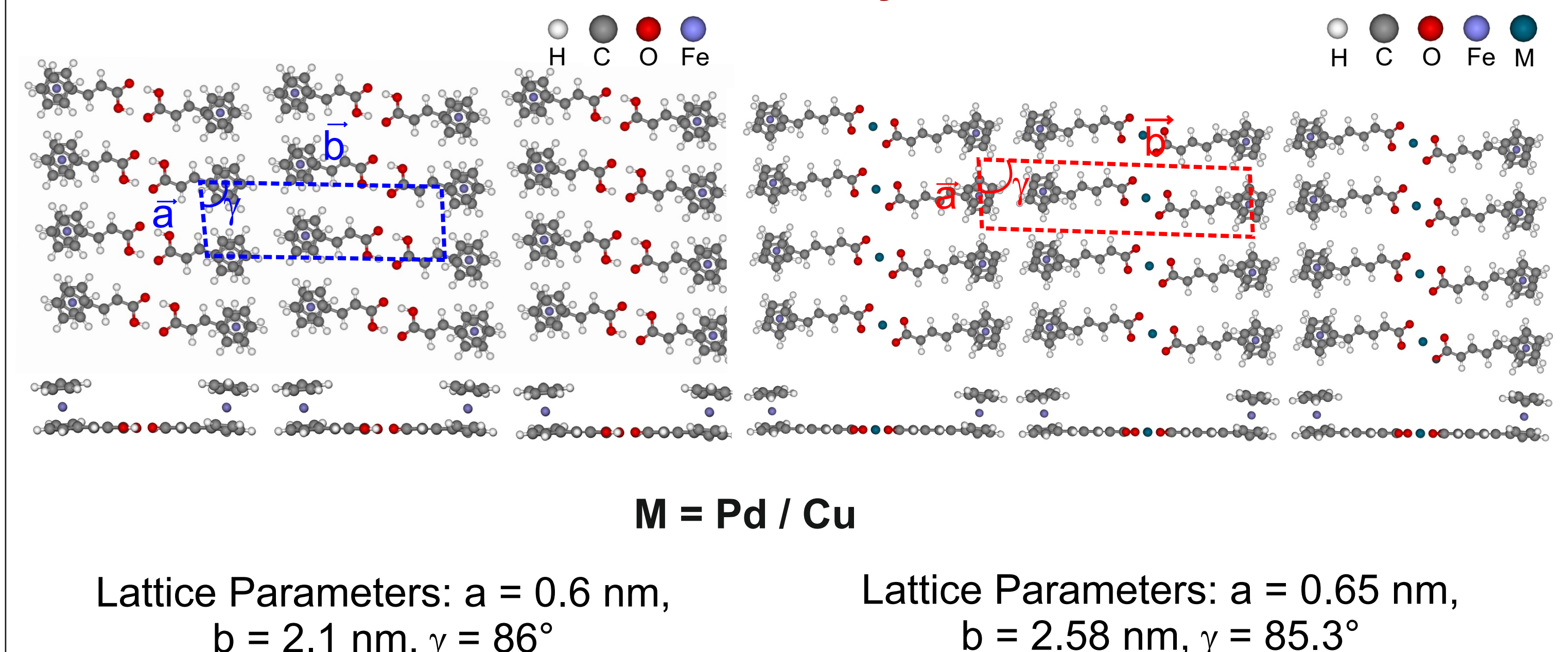
AFM phase images of SMONs of FcC3-Pd and FcC5-Pd



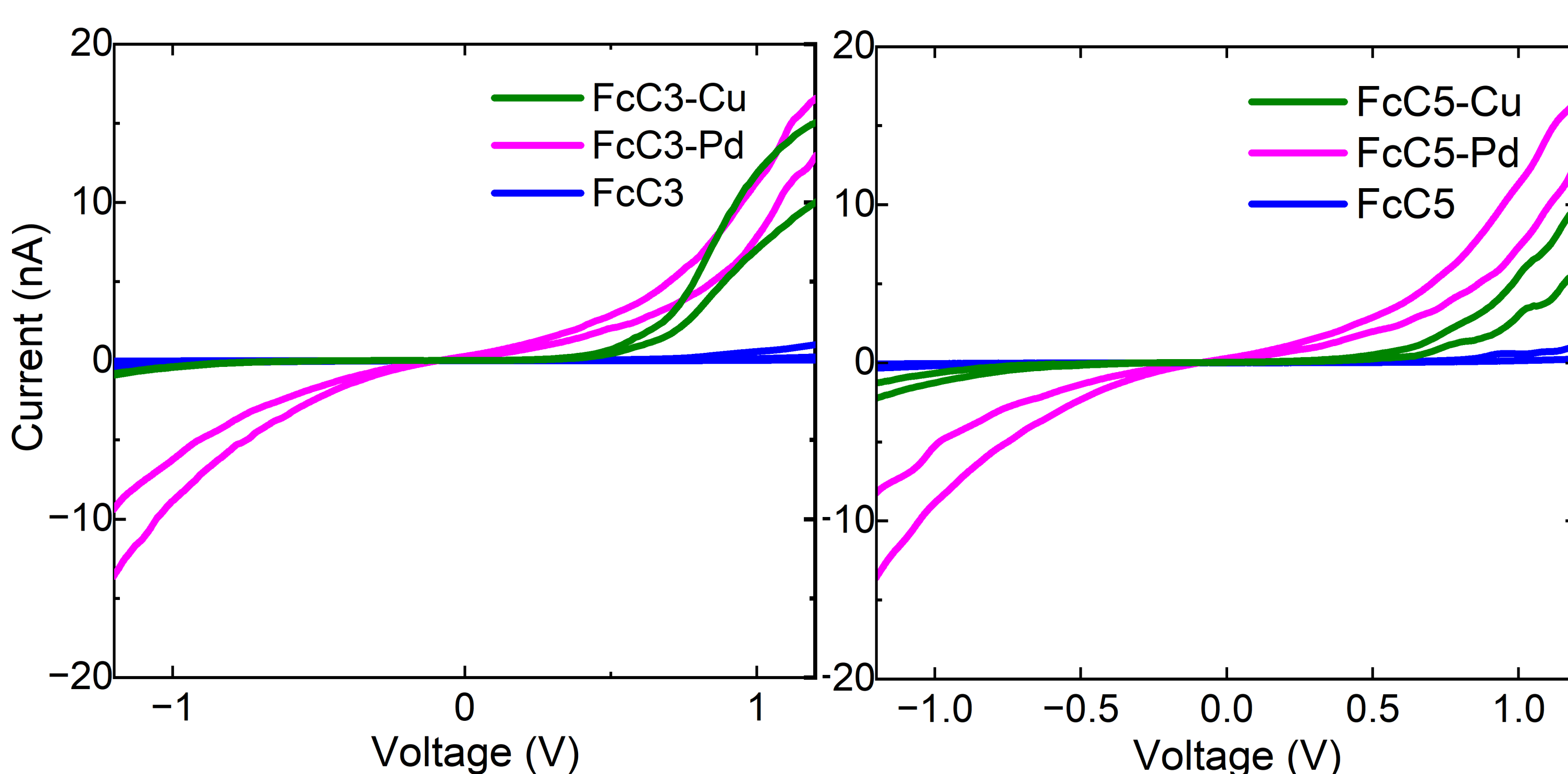
AFM phase images of SMONs of FcC3-Cu and FcC5-Cu



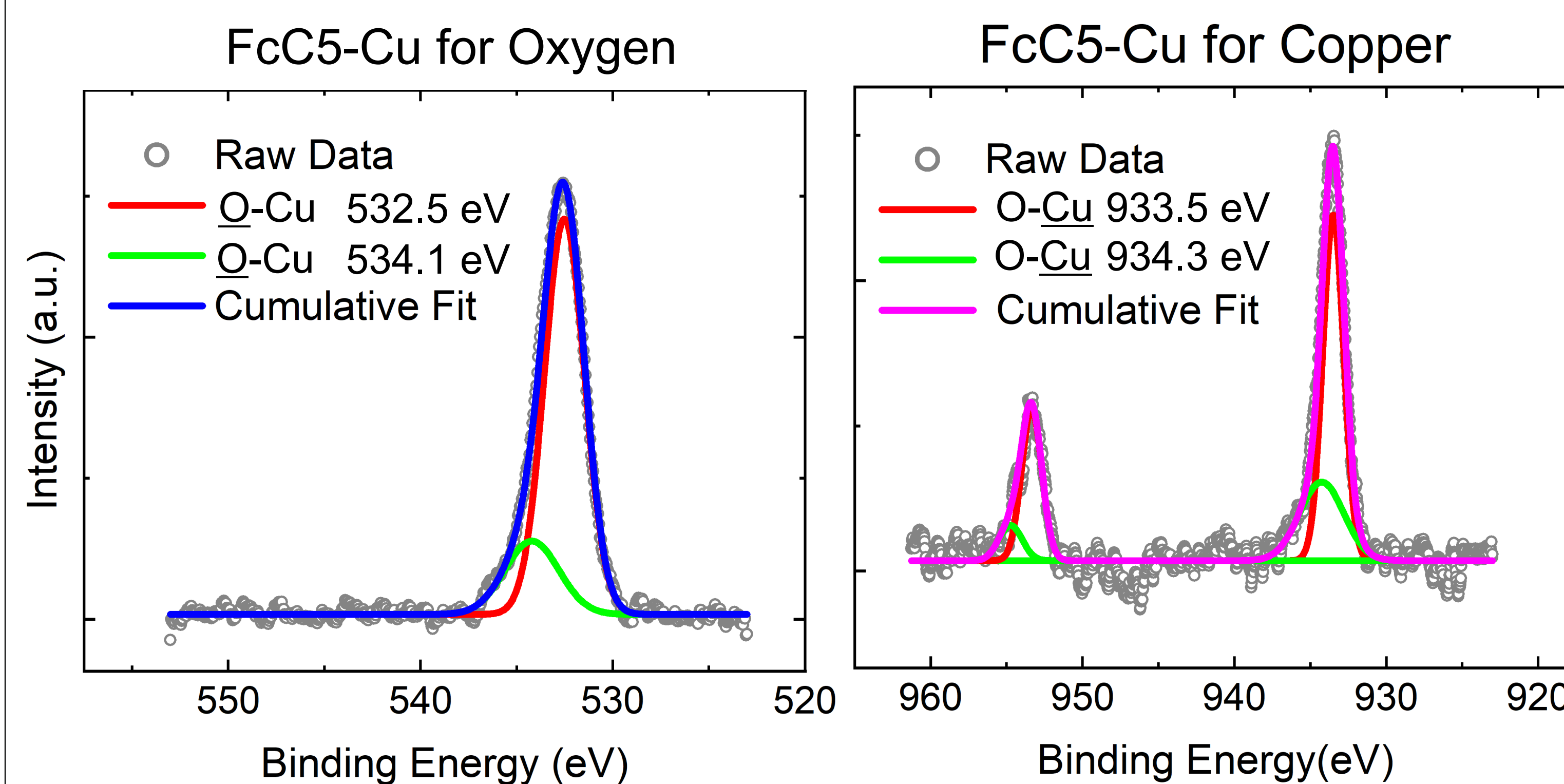
Tentative molecular model for adlayer of FcC3 and FcC5-M



I-V measurements of adlayer and SMON of FcC3/FcC5



XPS Analysis of FcC5-Cu



Summary

- Using AFM and STM, we have investigated the growth patterns of adlayer of FcC3 and FcC5 with and without Pd/Cu metal on HOPG at ambient conditions.
- Conductivity of adlayer and SMONs are measured using conductive AFM in contact mode. Results show that Pd/Cu-doped SMONs exhibit significantly higher conductivity compared to undoped adlayer.
- Using XPS we show the coordination of Pd/Cu in the SMON.
- We attribute a reduction in the HOMO-LUMO gap for the increased conductivity in SMON.

References

- 1) Mishra, V.; Gopakumar, T. G. Comparing interactions in three-fold symmetric molecules at solid-air interface. *Surf. Sci.* **2019**, 680, 11–17.
- 2) Mishra, V.; Mir, S. H.; Singh, J. K.; Gopakumar, T. G. Rationally Designed Semiconducting 2D Surface-Confined Metal-Organic Network. *ACS Appl. Mater. Interfaces*. **2020**, 12, 51122–32.

Acknowledgement

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